



Maximum Ratings

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	40°C to +85°C
Supply Voltage V _{CC}	0.5V to +7.0V
DC Switch Voltage V _S	
DC Input Voltage V _{IN}	0.5V to +7.0V
DC Output Current V _{OUT}	128mA
DC V _{CC} or Ground Current $I_{CC} / I_{GND} \dots \dots$	±100mA
Junction Temperature under Bias (TJ)	150 °C
Junction Lead Temperature (TL)	
(Soldering, 10 seconds)	
ESD (HBM)	5KV
Power Dissipation (PD) @ +85 °C	SOT23 250mW
	SC70 200mW
	UDFN1x1 150mW

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{CC}	Operating Voltage	-	1.65	-	5.5	V
V_{IN}	Control Input Voltage	-	0	-	V _{CC}	V
Vs	Switch Input Voltage	-	0	-	V _{CC}	V
V _{OUT}	Output Voltage	-	0	-	V _{CC}	V
T_A	Operating Temperature	-	-40	25	85	${}^{\mathbb{C}}$
+ +	Input Diss and Fall Time	Control Input $V_{CC} = 2.7V$ to $3.6V$	0	-	10	ns/V
t _r , t _f	Input Rise and Fall Time	Control Input $V_{CC} = 4.5V$ to $5.5V$	0	-	5	ns/V

Note: Control input must be held HIGH or LOW; it must not float.

All trademarks are property of their respective owners. 2017-01-0009





DC Electrical Characteristics

 $(T_A = -40$ °C to 85 °C, unless otherwise noted.)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units	
V _{IAR}	Analog Input Signal Range	-	V _{CC}	0	-	V _{CC}	V	
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$		-	0.7	1.1		
		$I_0 = 100 \text{mA}, V_{IN} = 2.4 \text{V}$	4.5V	-	0.6	1.0		
		$I_{O} = 100 \text{mA}, V_{IN} = 4.5 \text{V}$		-	0.8	1.2		
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	3.0V	-	0.8	1.3		
R _{ON}	ON Resistance ⁽¹⁾	$I_{O} = 100 \text{mA}, V_{IN} = 3.0 \text{V}$	5.0 V	-	0.9	1.9	Ω	
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	2.3V	-	1.0	1.5		
		$I_0 = 100 \text{mA}, V_{IN} = 2.3 \text{V}$	2.3 V	-	1.2	1.8		
	-	$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	1.65V	-	1.3	1.9		
	-	$I_0 = 100 \text{mA}, V_{IN} = 1.65 \text{V}$	- 1.65V	-	2.0	2.8		
		$I_A = 100 \text{mA}, V_{Bn} = 3.15 \text{V}$	4.5V	-	0.01	0.03		
۸D	ON Resistance Match	$I_A = 100 \text{mA}, V_{Bn} = 2.1 \text{V}$	3.0V	-	0.02	0.04		
ΔR_{ON}	Between Channels ^(1,2,3)	$I_A = 100 \text{mA}, V_{Bn} = 1.6 \text{V}$	2.3V	-	0.03	0.06	Ω	
		$I_A = 100 \text{mA}, V_{Bn} = 1.15 \text{V}$	1.65V	-	0.03	0.06		
R _{ONF}	ON Resistance Flatness ^(1,2,4)	$I_A = 100 \text{mA}, V_{Bn} = 0V, 2.4V, 4.5V$	4.5V	-	0.2	0.4		
		$I_A = 100 \text{mA}, V_{Bn} = 0V, 1.5V, 3.3V$	3.3V	-	0.2	0.4		
		$I_A = 100 \text{mA}, V_{Bn} = 0V, 1.1V, 2.5V$	2.5V	-	0.4	0.6	Ω	
		$I_A = 100 \text{mA}, V_{Bn} = 0 \text{V}, 0.7 \text{V}, 1.8 \text{V}$	1.8V	-	1.0	1.4		
	Input High Voltage		$V_{CC} = 1.65 V$	0.9	-	-		
				$V_{CC} = 2.3 V$	1.0	-	-	
V_{IH}		ut High Voltage Logic High Level $V_{CC} =$	$V_{CC} = 3V$	1.1	-	-	V	
			$V_{CC} = 4.2V$	1.2	-	-		
			$V_{\rm CC} = 5.5 V$	1.3	-	-		
	Input Low Voltage		$V_{CC} = 1.65V$	-	-	0.6		
V		Logic Low Level	$V_{CC} = 2.3V$	-	-	0.6	v	
V _{IL}		Logic Low Level	$\frac{V_{CC} = 3V}{V_{CC} = 4.2V}$	-	-	0.8	v	
			$V_{CC} = 4.2 V$ $V_{CC} = 5.5 V$	-	_	0.8	_	
$I_{OFF(NO)}$ or $I_{OFF(NC)}$	Source Off Leakage Current	V _{CC} =5.5V, VA =1V, 4.5V VBn =1V, 4.5V	$V_{\rm CC} = 3V$	-20	-	+20		
$I_{NC(ON)},$ $I_{NO(ON)},$ $I_{COM (ON)}$	Channel On Leakage Current	-	$V_{CC} = 1.65$ to $5.5V$	-40	-	+40	nA	
	Quiescent Supply	All channels ON or OFF,	$V_{CC} = 3.6V$	-	0.002	0.1		
I _{CC}	Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	$V_{\rm CC} = 5.5 V$	-	0.002	0.1	- μΑ	
I _{CCT}	Increase in I _{CC} per Input	Input at 2.7V	$V_{\rm CC} = 4.3 V$	-	0.2	10.0	μA	

Notes:

1. Measured by voltage drop between A and B pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (A or B).

2. Parameter is characterized but not tested in production.

3. $\Delta R_{ON} = R_{ON} \text{ max} - R_{ON} \text{ min.}$ measured at identical V_{CC}, temperature and voltage levels.

4. Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions.

All trademarks are property of their respective owners.

www.diodes.com





Capacitance (1)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
C _{IN}	Control Input		-	3.5	-	
C _{IO-B}	For B Port, Switch OFF	$V_{CC} = 5.0V, f = 1 MHz, T_A=25 C$	-	15.0	-	рF
C _{IOA-ON}	For A Port, Switch ON		-	34.0	-	r -

Notes:

1. Capacitance is characterized but not tested in production

Switch and AC Characteristics (1)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units	
t	Break Before	See Figure 2	$V_{\rm CC} = 2.7 \text{V}$ to 3.6 V	-	10	20		
t _{BBM}	Make Time	See Figure 2	$V_{\rm CC} = 4.5 \text{V to } 5.5 \text{V}$	-	6	12		
t	Turn on Time	See Figure 1	$V_{\rm CC} = 2.7 \text{V}$ to 3.6V	-	12	25		
t _{on}	Turn on Time		$V_{\rm CC} = 4.5 V$ to 5.5 V	-	9	18	ns	
t	Turn off Time	Soo Eiguro 1	$V_{\rm CC} = 2.7 \text{V}$ to 3.6 V	-	17	35		
t _{off}	Turn off Time	See Figure 1	$V_{\rm CC} = 4.5 V$ to 5.5 V	-	10	20		
Q Charge Injection	Charge	$C_{L} = 1nF, V_{GEN} = 0V,$ $R_{GEN} = 0\Omega.$ See Figure 3	$V_{\rm CC} = 5.0 V$	-	35	-	pC	
	Injection		$V_{CC} = 3.3 V$	-	25	-		
OIRR	Off Isolation	$\begin{split} & \textbf{R}_{L} = 50\Omega, \textbf{V}_{GEN} = 0\textbf{V}, \\ & \textbf{R}_{GEN} = 0\Omega, \textbf{f} = 1\textbf{MHz}. \\ & \textbf{See Figure 4}^{(2)} \end{split}$	$V_{\rm CC}$ =1.65V to 5.5V	-	-70	-	dB	
X _{TALK}	Crosstalk Isolation	f=1MHz, See Figure 5	$V_{CC} = 1.65 V$ to 5.5V	-	-70	-		
f3dB	-3dB Bandwidth	See Figure 8	$V_{\rm CC}$ =1.65V to 5.5V	-	150	-	MHz	
T _{HD}	Total Harmonic Distortion	R_L =600Ω, V_{IN} =0.5Vpp, f=20Hz to 20kHz See Figure 9	$V_{\rm CC} = 2.7 V$ to $4.2 V$	-	0.015	-	%	

Notes:

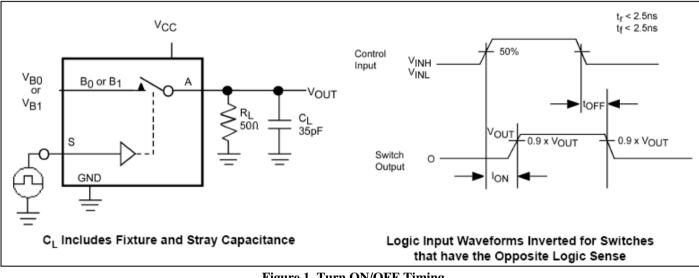
1. Guaranteed by design.

2. Off Isolation = 20 Log₁₀ [V_{Bn}/V_A] and is measured in dB.





Test Circuits and Timing Diagrams





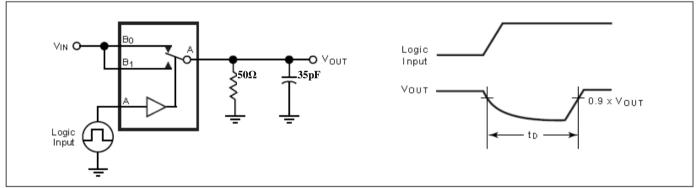


Figure 2. Break Before Make Interval Timing

All trademarks are property of their respective owners. 2017-01-0009





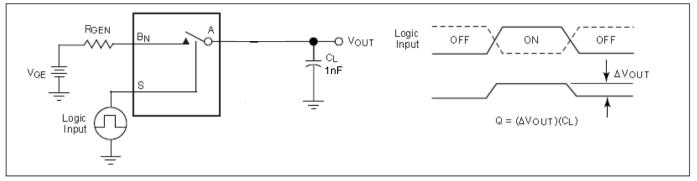


Figure 3. Charge Injection Test

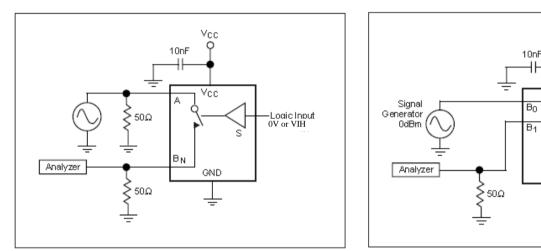


Figure 4. Off Isolation

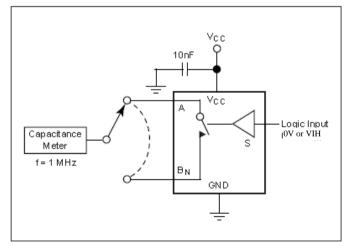


Figure 6. Channel Off Capacitance

Figure 5. Crosstalk

Vcc

Vcc

GND

÷

ŝ

<u>ξ</u>50Ω

-11-

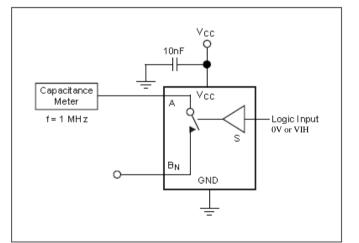


Figure 7. Channel On Capacitance

All trademarks are property of their respective owners. 2017-01-0009





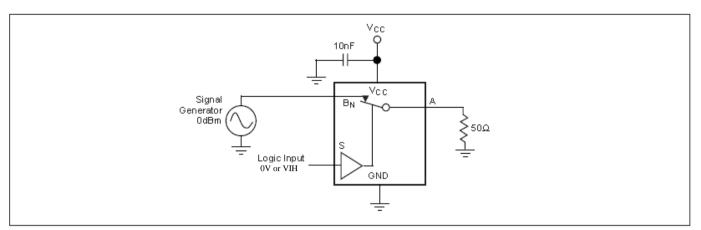


Figure 8. Bandwidth

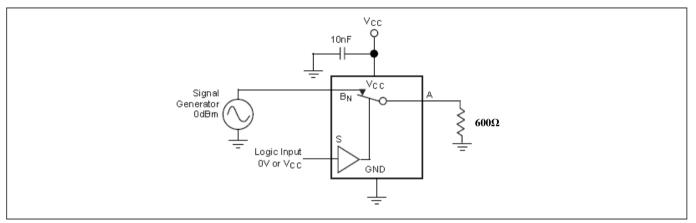


Figure 9. Harmonic Distortion

All trademarks are property of their respective owners. 2017-01-0009

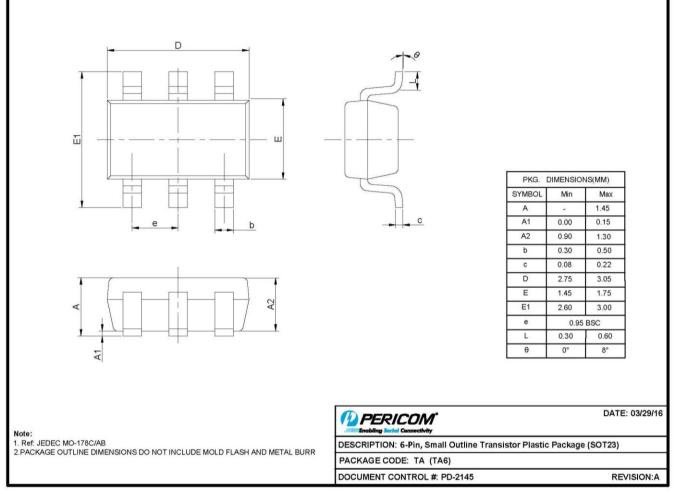


A Product Line of Diodes Incorporated



Mechanical Information

TA (6-pin SOT23)

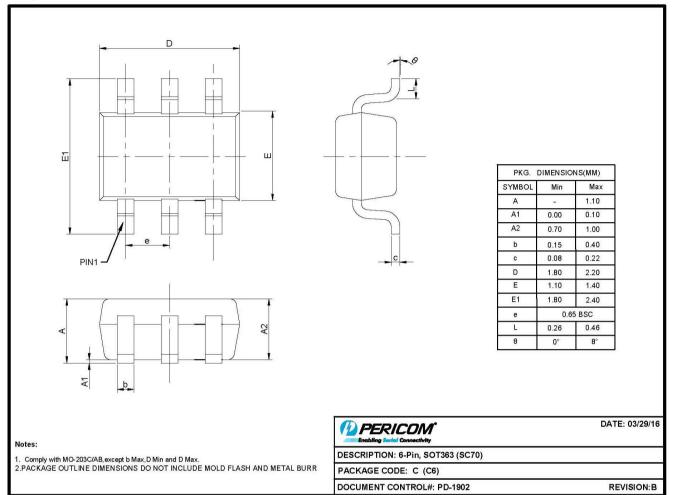


16-0082





C (6-pin SC70)

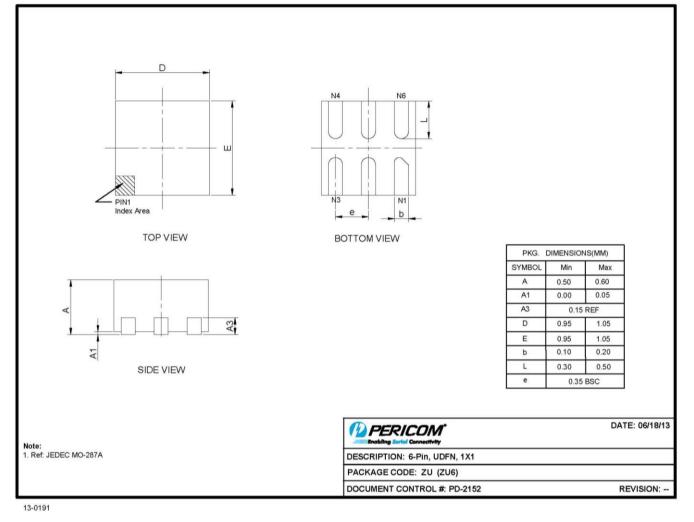


16-0078

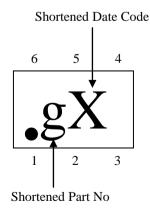




ZU (6-pin UDFN 1x1)



Marking Description







Note: For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

Ordering Information

Part Number	Package Code	Package	Top Marking
PI5A4157CEX	С	6-Pin, SOT363 (SC70), Tape & Reel	mA
PI5A4157TAEX	ТА	6-Pin, Small Outline Transistor Plastic Package (SOT23), Tape & reel	mA
PI5A4157ZUEX	ZU	6-Pin, 1x1 (UDFN), Tape & reel	g

Notes:

• Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

• E = Pb-free and Green

• X suffix = Tape/Reel

All trademarks are property of their respective owners. 2017-01-0009





PI5A4157

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the

failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated www.diodes.com